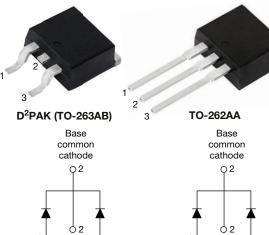
www.vishay.com

VS-20CTQ150S-M3, VS-20CTQ150-1-M3

Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 10 A



10 Common 0 3 Anode cathode Anode VS-20CTQ150S-M3

1 Common 3 Anode cathode Anode VS-20CTQ150-1-M3

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>R</sub>	150 V				
V <sub>F</sub> at I <sub>F</sub>	0.66 V				
I <sub>RM</sub> max.	5.0 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
E <sub>AS</sub>	1.0 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

### FEATURES

- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	20	А		
V <sub>RRM</sub>		150	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1030	А		
V <sub>F</sub>	10 A <sub>pk</sub> , $T_J$ = 125 °C (per leg)	0.66	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20CTQ150S-M3 VS-20CTQ150-1-M3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	150			
Maximum working peak reverse voltage	V <sub>RWM</sub>	– 150 V			

Revision: 27-Oct-17 1 Document Number: 95731 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

## Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward per leg					10			
current See fig. 5	per device	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 154 °C	, rectangular waveform	20	А		
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated	1030	A		
		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	180			
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 2 mH		1.0	mJ		
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		1	А		

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS TYP. MAX.				UNITS		
		10 A	T <sub>.1</sub> = 25 °C	0.80	0.88			
Maximum forward voltage drop per leg See fig. 1	<b>V</b> (1)	20 A	1j=25 C	0.90	1.0	V		
	V <sub>FM</sub> <sup>(1)</sup>	10 A	T 405 00	0.63	0.66			
		20 A	T <sub>J</sub> = 125 °C	0.73	0.77			
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	3.0	25	μA		
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	2.7	5.0	mA		
Typical junction capacitance per leg	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	280	pF		
Typical series inductance per leg	Ls	Measured lead to lead 5 mm from package body -			8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> - 10 000				V/µs		

#### Note

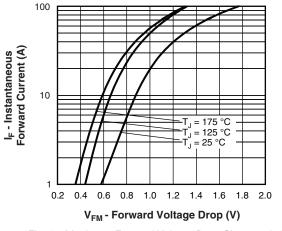
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

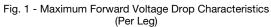
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance,	per leg	P a	DC operation	2.0		
junction to case	per package	R <sub>thJC</sub>	DC Operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (Only for TO-262)	0.50		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Manutina tanana				6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
			Case style D <sup>2</sup> PAK (TO-263AB)	20CTC	150S	
Marking device			Case style TO-262AA	20CTQ	150-1	

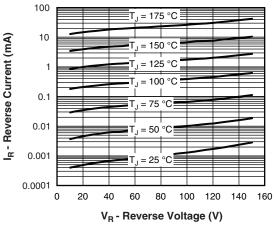
# VS-20CTQ150S-M3, VS-20CTQ150-1-M3

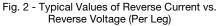












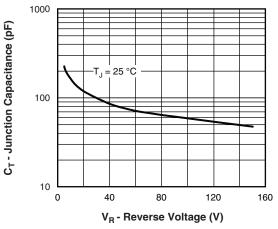


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

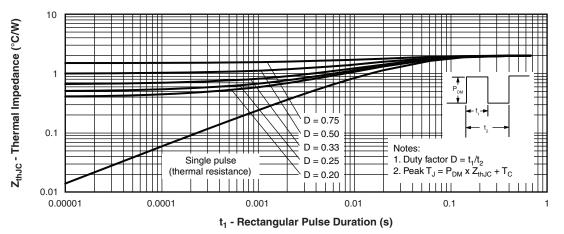
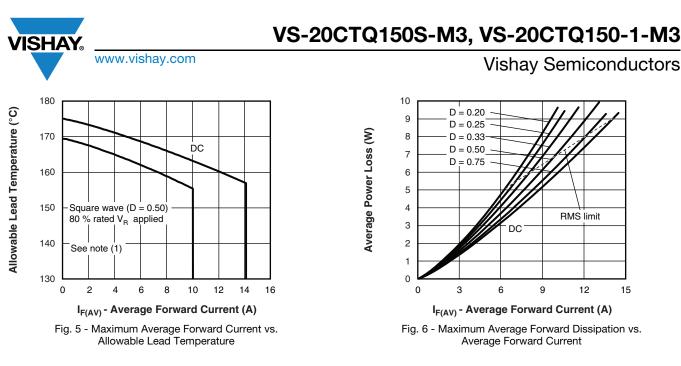


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



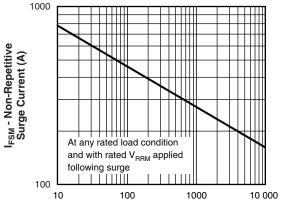




Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

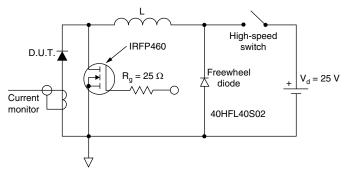


Fig. 8 - Unclamped Inductive Test Circuit

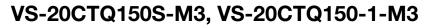
### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$

Revision: 27-Oct-17

4

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

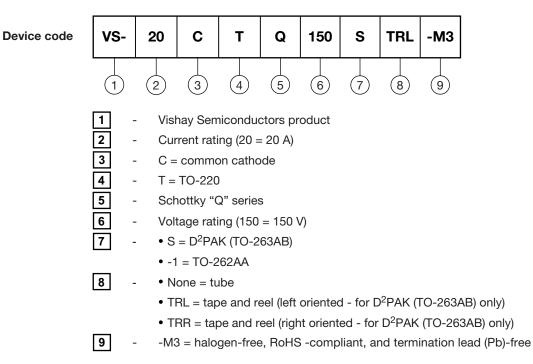


### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**

www.vishay.com

SHA



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20CTQ150S-M3	50	1000	Antistatic plastic tubes			
VS-20CTQ150STRL-M3	800	800	13" diameter reel			
VS-20CTQ150STRR-M3	800	800	13" diameter reel			
VS-20CTQ150-1-M3	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Dout marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			

# **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

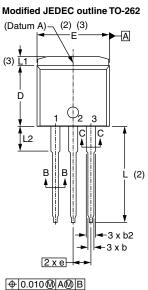


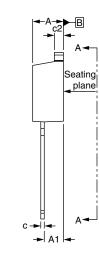
## **Outline Dimensions**

**Vishay Semiconductors** 

**TO-262** 

### **DIMENSIONS** in millimeters and inches

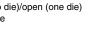


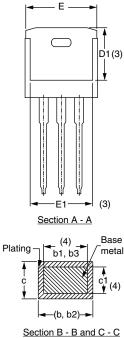


Lead assignments



**Diodes** 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

CVMDOI	MILLIM	ETERS	INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

Revision: 04-Oct-10

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

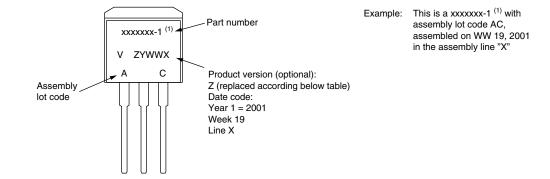
<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Document Number: 95419 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



## **Vishay Semiconductors**

**TO-262** 



#### Note

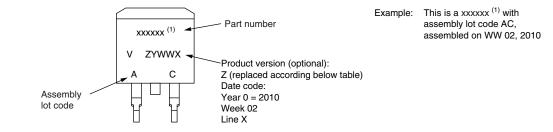
<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z) PRODUCT DEFINITION				
A Termination lead (Pb)-free				
B Totally lead (Pb)-free				
E	RoHS-compliant and termination lead (Pb)-free			
F RoHS-compliant and totally lead (Pb)-free				
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free			
Ν	Halogen-free, RoHS-compliant and totally lead (Pb)-free			
G	Green			



## **Vishay Semiconductors**

D<sup>2</sup>PAK



#### Note

<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
А	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

CUS06(TE85L,Q,M) MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR30H100MFST1G MMBD301M3T5G PMAD1103-LF PMAD1108-LF RB160M-50TR RB520S-30 RB551V-30 DD350N18K DZ435N40K DZ600N16K BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327 IDL02G65C5XUMA1 NSR05F40QNXT5G NSVR05F40NXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SBAT54CWT1G SBM30-03-TR-E SBS818-TL-E SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS 70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK110-LTP